

NDT014L-VB Datasheet N-Channel 60-V (D-S) MOSFET

PRODUC	CT SUMMARY		
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)
<u></u>	0.076 at V _{GS} = 10 V	4.5	10 nC
60	0.085 at V_{GS} = 4.5 V	3.5	TOTIC

FEATURES

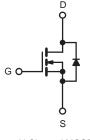
- Halogen-free
- TrenchFET[®] Power MOSFET



APPLICATIONS

· Load Switches for Portable Devices





N-Channel MOSFET

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage		V _{GS}	± 20	v
	T _C = 25 °C		4.5	
Continuous Drain Current (T ₁ = 150 °C)	T _C = 70 °C	I _D	3.2 ^a	
	T _A = 25 °C	- U	2.7	
	T _A = 70 °C		2.3	A
Pulsed Drain Current		I _{DM}	20	
Continuous Source-Drain Diode Current	T _C = 25 °C	I _S	3.2	
Continuous Cource Drain Diode Current	T _A = 25 °C	'5	2.1 ^{b, c}	
	T _C = 25 °C		4.0	
Maximum Power Dissipation	T _C = 70 °C	P _D	3.0	w
Maximum Fower Dissipation	T _A = 25 °C		2.5 ^{b, c}	VV
	T _A = 70 °C		1.6 ^{b, c}	
Operating Junction and Storage Temperatur	e Range	T _J , T _{stg}	- 55 to 150	°C
Soldering Recommendations (Peak Temperations)	ature) ^{e, f}		260	U

THERMAL RESISTANCE BATINGS

Parameter		Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient ^{a, c, d} $t \le 5 s$		R _{thJA}	40	50	°C/W			
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	15	20				

Notes:

a. Package limited, T_C = 25 °C.
b. Surface Mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. Maximum under Steady State conditions is 95 °C/W.

e. See Reliability Manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

f. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

unless othe	erwise noted				
Symbol	Test Conditions	Min.	Тур.	Max.	Unit
				-	
V _{DS}	$V_{GS} = 0 V, I_{D} = 250 \mu A$	60			V
$\Delta V_{DS}/T_{J}$	In - 250 uA		25		
$\Delta V_{GS(th)}/T_J$	ID = 230 μΛ		- 4.0		mV/°C
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.0		2.5	V
I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA
I _{DSS}	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 60 \text{ V}, V_{CS} = 0 \text{ V}, T_{1} = 55 \text{ °C}$			1	μA
D()		30		10	A
'D(on)		50	0.076		~
R _{DS(on)}					Ω
0.	$v_{GS} = 4.5 v, i_D = 3.0 A$ 0.0				6
9 _{fs}	V _{DS} = 10 V, 1 _D = 4.0 A		40	[S
			910	[
	(1 - 20)(1)(1 - 0)(1 - 1)				pF
	$v_{\rm DS} = 30v, v_{\rm GS} = 0v, i = 1 \text{ MHz}$				
C _{rss}					
Qg	$V_{DS} = 30$ V, $V_{GS} = 10$ V, $I_D = 4.0$ A		22 10	33 15	
Q _{gs}	V_{DS} = 30 V, V_{GS} = 4.5 V, I_{D} = 3.0 A		2.5		nC
			1.7		
	f = 1 MHz		2.4		Ω
-			15	25	
t _r	$V_{DD} = 30V, R_1 = 1.5 \Omega$		10	15	
t _{d(off)}	$I_D \cong 4.0 \text{ A}, \text{ V}_{\text{GEN}} = 4.5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		35	55	1
t _f	BD E		12	20	-
t _{d(on)}			10	15	ns
	$V_{DD} = 30V, R_1 = 1.5 \Omega$		12	20	-
	$I_D \cong 4.0 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		25	40	
			10	15	
cs				I	I
I _S	T _C = 25 °C			7.2	
-			1	30	A
V _{SD}	$I_{S} = 4.0 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V
			20	40	ns
			10	20	nC
ta	I _F = 4.0 A, dl/dt = 100 A/μs, T _J = 25 °C		10		- ns
			•		
	$\begin{tabular}{ c c c } \hline Symbol \\ \hline V_{DS} \\ \hline $\Delta V_{DS} / T_J$ \\ \hline $\Delta V_{GS}(th) / T_J$ \\ \hline $\Delta V_{GS}(th) / T_J$ \\ \hline $V_{GS}(th) \\ \hline I_{GSS} \\ \hline I_{DSS} \\ \hline I_{CSS} \\ \hline I_{CSS} \\ \hline I_{SM} \\ \hline V_{SD} \\ \hline t_{rr} \\ \hline t_{rr} \\ \hline I_{SM} \\ \hline V_{SD} \\ \hline t_{rr} \\ \hline T_{rr} \\ \hline U_{Cr} \\ \hline \hline U_{Cr} \\ \hline U_{Cr} \\ \hline \hline \hline U_{Cr} \\ \hline \hline \hline U_{Cr} \\ \hline \hline \hline $$	$\begin{tabular}{ c c c c } \hline V_{DS} & V_{GS} = 0 \ V, \ I_{D} = 250 \ \mu A \\ \hline \Delta V_{DS} \ / T_{J} & I_{D} = 250 \ \mu A \\ \hline \Delta V_{GS(th)} \ & V_{DS} = V_{GS} \ . \ I_{D} = 250 \ \mu A \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = 12 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_{J} = 55 \ ^{\circ}C \\ \hline I_{D(on)} & V_{DS} \ge 5 \ V, \ V_{GS} = 4.5 \ V \\ \hline V_{DS} = 60 \ V, \ I_{D} = 3.0 \ A \\ \hline V_{GS} = 4.5 \ V, \ I_{D} = 3.0 \ A \\ \hline V_{DS} = 10 \ V, \ I_{D} = 4.0 \ A \\ \hline Q_{GS} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_{D} = 4.0 \ A \\ \hline Q_{Gg} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_{D} = 4.0 \ A \\ \hline Q_{gd} & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_{D} = 3.0 \ A \\ \hline Q_{gd} & V_{DS} = 30 \ V, \ V_{GS} = 4.5 \ V, \ I_{D} = 3.0 \ A \\ \hline Q_{gd} & I_{D} = 4.0 \ A, \ V_{GEN} = 4.5 \ V, \ R_{g} = 1 \ \Omega \\ \hline I_{d} (off) & I_{D} = 4.0 \ A, \ V_{GEN} = 4.5 \ V, \ R_{g} = 1 \ \Omega \\ \hline I_{d} (off) & I_{D} = 4.0 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \\ \hline I_{d} = 4.0 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \\ \hline I_{S} & T_{C} = 25 \ ^{\circ}C \\ \hline I_{SM} & V_{SD} & I_{S} = 4.0 \ A, \ V_{GS} = 0 \ V \\ \hline I_{rr} & I_{F} = 4.0 \ A, \ dI/dt = 100 \ A/\mu_{S}, \ T_{I} = 25 \ ^{\circ}C \\ \hline \end{tabular}$	$\begin{tabular}{ c c c c c } \hline Symbol & Test Conditions & Min. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 60 \\ \hline \Delta V_{DS} / T_J & I_D = 250 \ \mu A & 1.0 \\ \hline I_D = 250 \ \mu A & 1.0 \\ \hline V_{GS}(th) & V_{DS} = V_{GS} \ I_D = 250 \ \mu A & 1.0 \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 12 \ V & V_{DS} = 60 \ V, \ V_{GS} = 0 \ V & V_{DS} = 50 \ V & V_{DS} = 60 \ V, \ V_{GS} = 0 \ V & V_{DS} = 50 \ V & V_{DS} = 10 \ V, \ I_D = 4.0 \ A & V_{CS} = 10 \ V, \ I_D = 4.0 \ A & V_{DS} = 10 \ V, \ I_D = 4.0 \ A & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 4.0 \ A & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 4.0 \ A & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 3.0 \ A & V_{DS} = 10 \ V, \ I_D = 3.0 \ A & V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 4.0 \ A & V_{DS} = 10 \ V, \ I_D = 4.0 \ A & V_{DD} = 30V, \ R_g = 1 \ \Omega & V_{DS} = 10 \ V, \ I_D = 4.0 \ A, \ V_{GS} = 10 \ V, \ R_g = 1 \ \Omega & V_{DS} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 30V, \ R_g = 1 \ \Omega & V_{DS} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 30V, \ R_g = 1 \ \Omega & V_{DS} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 30V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 30V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V, \ R_g = 1 \ \Omega & V_{DD} = 10 \ V_{DD} = 10 \ V, \ R_g = 1 \ U_{D} = 10 \ V_{DD} = 10 \ V_{DD} = 10 \ V_{DD} = 10 \ V_{DD} = 10 \ $	$\begin{tabular}{ c c c c c } \hline Symbol & Test Conditions & Min. Typ. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 60 & 25 & 00 & 00 & 00 & 00 & 00 & 00 & 0$	$\begin{tabular}{ c c c c c c } \hline Symbol & Test Conditions & Min. Typ. Max. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 25 & 000 \ V_{GS} = 10 \ V_DS = 250 \ \mu A & -4.0 & 000 \ V_{GS} = 10 \ V_DS = 0 \ V_DS = 12 \ V & 11 & 000 \ V_DS = 60 \ V_{GS} = 0 \ V & 11 & 000 \ V_DS = 60 \ V_{GS} = 0 \ V & 11 & 000 \ V_DS = 60 \ V_{GS} = 0 \ V & 11 & 000 \ V_DS = 60 \ V_{GS} = 0 \ V & 11 & 000 \ V_DS = 60 \ V_{GS} = 0 \ V & 11 & 000 \ V_DS = 60 \ V_{GS} = 0 \ V \ U_S = 10 \ V, \ I_D = 50 \ V \ GS = 10 \ V, \ I_D = 50 \ V \ GS = 10 \ V, \ I_D = 3.0 \ A & 0.076 \ V_{GS} = 10 \ V, \ I_D = 4.0 \ A & 45 \ \hline \end{tabular}$

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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T_C = - 55

1.5

2.0

T_C = 125 °C

 $T_{\rm C} = 25$

1.0

V_{GS} - Gate-to-Source Voltage (V)

Transfer Characteristics

0.5

 \mathbf{C}_{iss}

Coss

15

30

V_{DS} - Drain-to-Source Voltage (V)

Capacitance

45

 $V_{GS} = 4.5 \text{ V}, 10 \text{ V}$

60

2rs

 $I_{\rm D} = 6.3 \, {\rm A}$

- 25

0

25

50

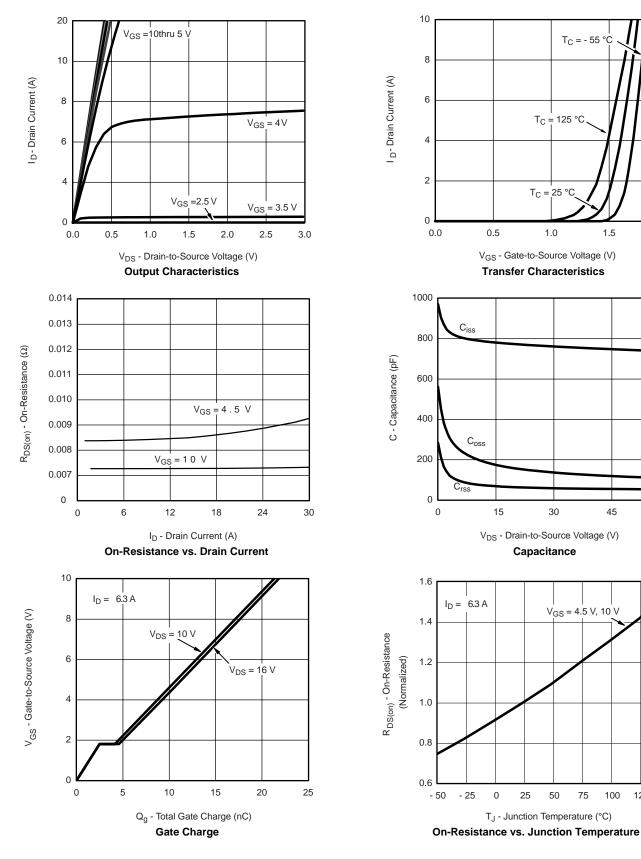
 T_J - Junction Temperature (°C)

75

100

125

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

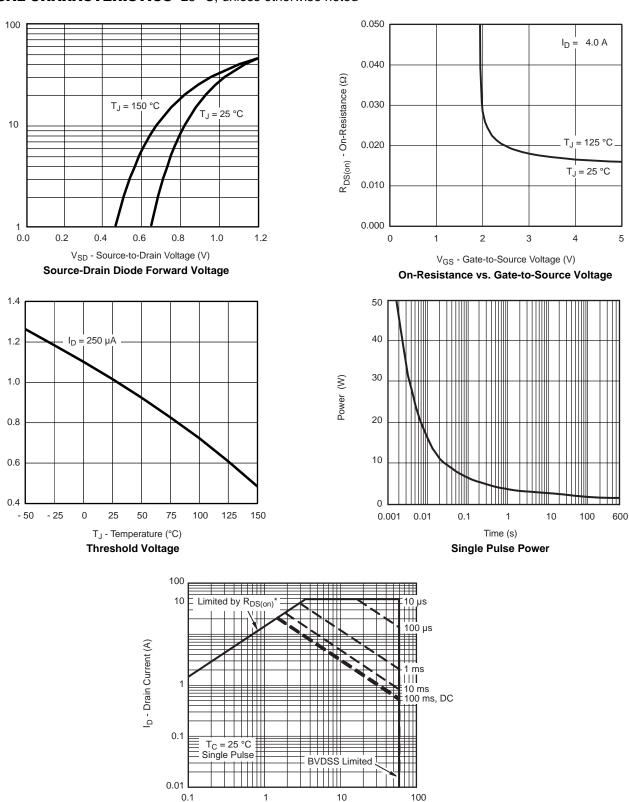




150

Is - Source Current (A)

V_{GS(th)} (V)



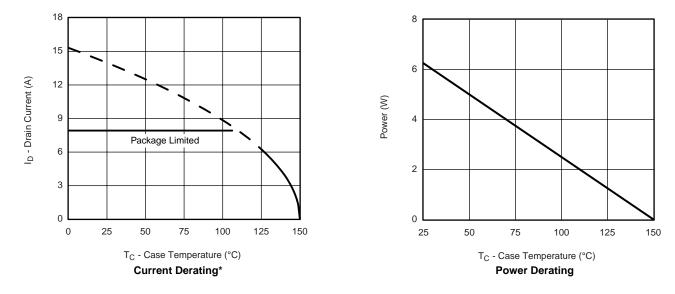
V_{DS} - Drain-to-Source Voltage (V) * V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified Single Pulse Power, Junction-to-Case

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

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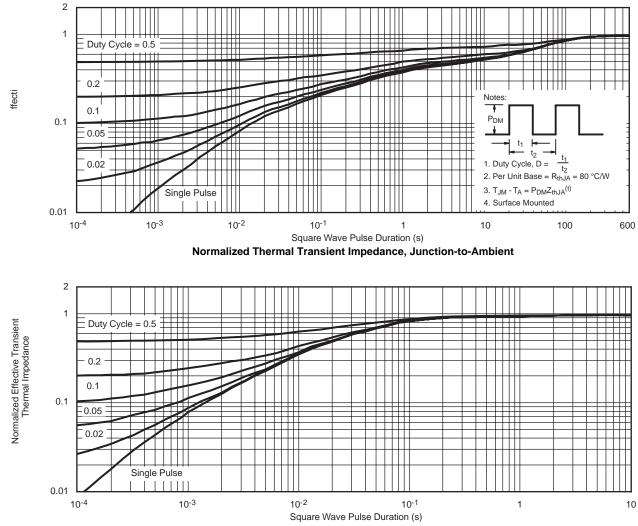




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



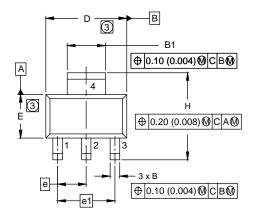


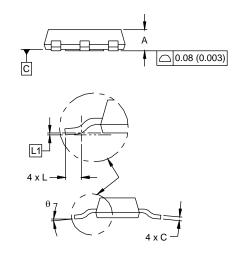
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Normalized Thermal Transient Impedance, Junction-to-Foot



SOT-223 (HIGH VOLTAGE)





DIM.	MILLI	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.		
А	1.55	1.80	0.061	0.071		
В	0.65	0.85	0.026	0.033		
B1	2.95	3.15	0.116	0.124		
С	0.25	0.35	0.010	0.014		
D	6.30	6.70	0.248	0.264		
E	3.30	3.70	0.130	0.146		
е	2.30 BSC		0.0905 BSC			
e1	4.60 BSC		0.181 BSC			
Н	6.71	7.29	0.264	0.287		
L	0.91	-	0.036	-		
L1	0.061 BSC		0.002	4 BSC		
θ	-	10'	-	10'		

Notes

1. Dimensioning and tolerancing per ASME Y14.5M-1994.

2. Dimensions are shown in millimeters (inches).

3. Dimension do not include mold flash.

4. Outline conforms to JEDEC outline TO-261AA.



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